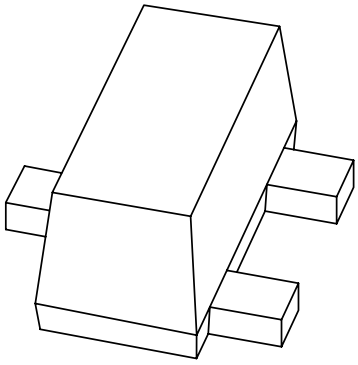
DATA SHEET



BC846F; BC847F; BC848F series
NPN general purpose transistors

Preliminary specification
Supersedes data of 1998 Nov 10

1999 May 18

Philips
Semiconductors

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NPN general purpose transistors BC846F; BC847F; BC848F series

FEATURES

- Power dissipation comparable to SOT23
- Low current (max. 100 mA)
- Low voltage (max. 65 V).

APPLICATIONS

- General purpose switching and amplification, especially in portable equipment.

DESCRIPTION

NPN transistor encapsulated in an ultra small SC-89 (SOT490) plastic SMD package.
PNP complements: BC856F, BC857F and BC858F series.

MARKING

TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE
BC846AF	1A	BC847CF	1G
BC846BF	1B	BC848AF	1J
BC847AF	1E	BC848BF	1K
BC847BF	1F	BC848CF	1L

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

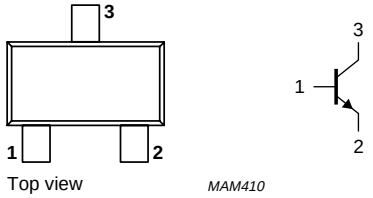


Fig.1 Simplified outline (SC-89; SOT490) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter			
	BC846AF; BC846BF		–	80	V
	BC847AF; BC847BF; BC847CF		–	50	V
	BC848AF; BC848BF; BC848CF		–	30	V
V_{CEO}	collector-emitter voltage	open base			
	BC846AF; BC846BF		–	65	V
	BC847AF; BC847BF; BC847CF		–	45	V
	BC848AF; BC848BF; BC848CF		–	30	V
V_{EBO}	emitter-base voltage	open collector	–	5	V
I_C	collector current (DC)		–	100	mA
I_{CM}	peak collector current		–	200	mA
I_{BM}	peak base current		–	100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C; note 1	–	250	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	in free air; note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

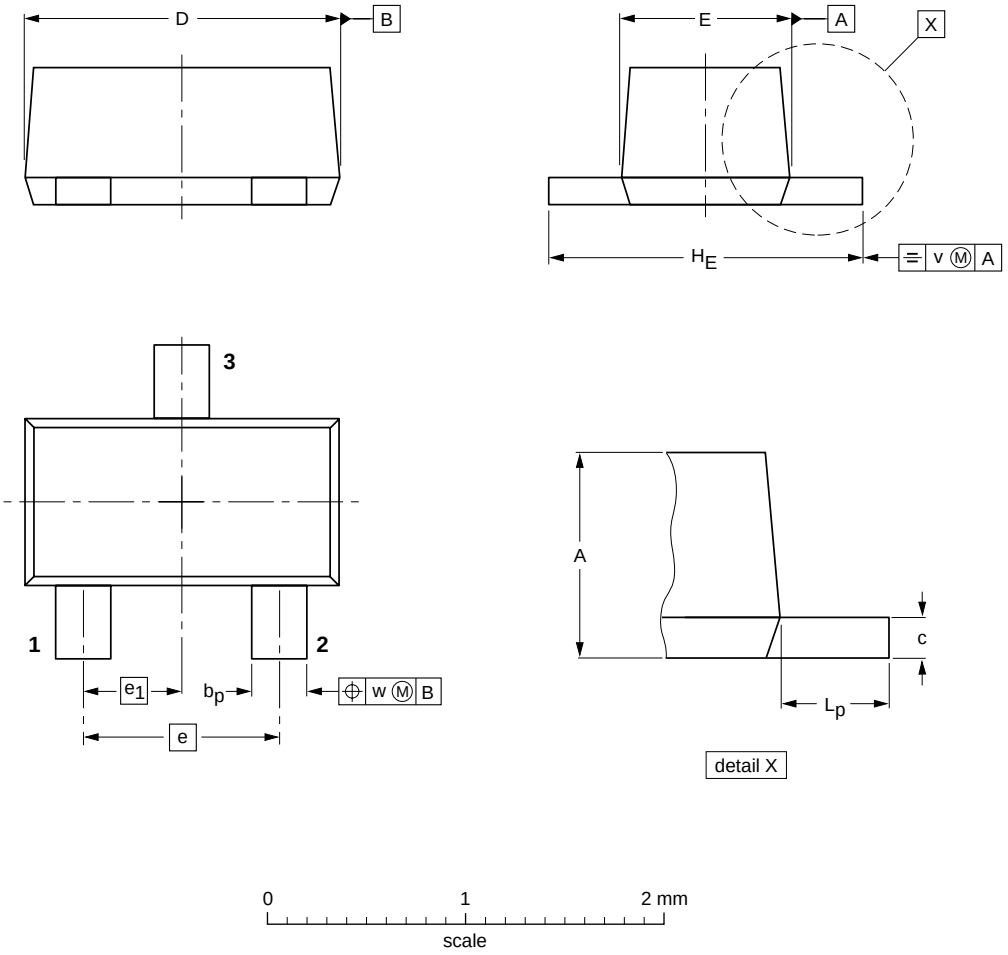
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	I_E = 0; V_{CB} = 30 V	–	15	nA
		I_E = 0; V_{CB} = 30 V; T_j = 150 °C	–	5	µA
I_{EBO}	emitter cut-off current	I_C = 0; V_{EB} = 5 V	–	100	nA
h_{FE}	DC current gain	I_C = 2 mA; V_{CE} = 5 V			
	BC846AF; BC847AF; BC848AF		110	220	
	BC846BF; BC847BF; BC848BF		200	450	
	BC847CF; BC848CF		420	800	
V_{CEsat}	collector-emitter saturation voltage	I_C = 10 mA; I_B = 0.5 mA	–	200	mV
		I_C = 100 mA; I_B = 5 mA; note 1	–	400	mV
V_{BE}	base-emitter voltage	I_C = 2 mA; V_{CE} = 5 V	580	700	mV
		I_C = 10 mA; V_{CE} = 5 V	–	770	mV
C_c	collector capacitance	$I_E = i_e$ = 0; V_{CB} = 10 V; f = 1 MHz	–	1.5	pF
f_T	transition frequency	I_C = 10 mA; V_{CE} = 5 V; f = 100 MHz	100	–	MHz
F	noise figure	I_C = 200 µA; V_{CE} = 5 V; R_S = 2 kΩ; f = 1 kHz; B = 200 Hz	–	10	dB

Note

1. Pulse test: $t_p \leq 300$ µs; $\delta \leq 0.02$.

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads **SOT490**



DIMENSIONS (mm are the original dimensions)

UNIT	A	b_p	c	D	E	e	e_1	H_E	L_p	v	w
mm	0.8 0.6	0.33 0.23	0.2 0.1	1.7 1.5	0.95 0.75	1.0	0.5	1.7 1.5	0.5 0.3	0.1	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT490			SC-89			98-10-23

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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